NSN 5962-01-424-5671

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View Online at https://aerobasegroup.com/nsn/5962-01-424-5671

Body	Length:

Between 0.442 inches and 0.460 inches

Body Width:

Between 0.442 inches and 0.460 inches

Body Height:

Between 0.060 inches and 0.100 inches

Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Pacer dawn

Features Provided:

Burn in, mil-std-883, class b and electrostatic sensitive and tested to mil-std-883 and monolithic and programmable

Inclosure Material:

Silicon

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

22 input

Criticality Code Justification:

Cbbl

Case Outline Source And Designator:

C-4 mil-m-38510

Current Rating Per Characteristic:

16.00 milliamperes reverse current, dc and 140.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, cmos, ultraviolet erasable, programmable logic array, monolithic silicon

Voltage Rating And Type Per Characteristic:

-2.0 volts input and 7.0 volts input and -0.5 volts power source and 7.0 volts power source and -0.5 volts output and 7.0 volts output

Capitance Rating Per Characteristic:

8.00 input picofarads and 8.00 output picofarads

Time Rating Per Chacteristic:

35.00 nanoseconds access

Memory Device Type:

Pal

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No Fiig: A458a0



Special Features:
Vend0r similar p/n atv750-35lm/883
Test Data Document:
$96906 \hbox{-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.}\\$
Terminal Type And Quantity:
28 leadless
Shelf Life:
N/a
Unit Of Measure:
Demilitarization: